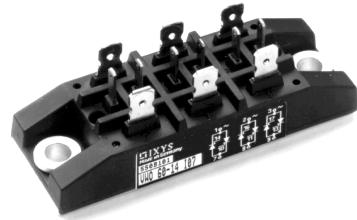
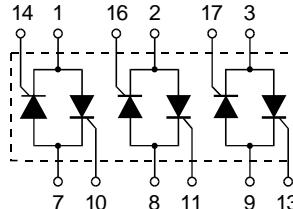


# Three Phase AC Controller Modules

$I_{RMS} = 3 \times 60 \text{ A}$   
 $V_{RRM} = 800-1600 \text{ V}$

Preliminary data

$V_{RSM}$ $V_{DSM}$ V	$V_{RRM}$ $V_{DRM}$ V	Type
800	800	VWO 60-08io7
1200	1200	VWO 60-12io7
1400	1400	VWO 60-14io7
1600	1600	VWO 60-16io7



Symbol	Test Conditions	Maximum Ratings		
$I_{RMS}$	$T_K = 85^\circ\text{C}$ , 50 - 400 Hz (per phase)	60	A	
$I_{TRMS}$	$T_{VJ} = T_{VJM}$	43	A	
$I_{TAVM}$	$T_K = 85^\circ\text{C}$ ; (180° sine)	27	A	
$I_{TSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $V_R = 0$	550 600	A A	
	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine			
	$T_{VJ} = T_{VJM}$ $V_R = 0$	500 550	A A	
	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine			
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	1520 1520	$\text{A}^2\text{s}$ $\text{A}^2\text{s}$	
	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine			
	$T_{VJ} = T_{VJM}$ $V_R = 0$	1250 1250	$\text{A}^2\text{s}$ $\text{A}^2\text{s}$	
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $f = 50 \text{ Hz}$ , $t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 0.45 \text{ A}$ $di_G/dt = 0.45 \text{ A}/\mu\text{s}$	repetitive, $I_T = 25 \text{ A}$  non repetitive, $I_T = I_{TAVM}$	150 500	$\text{A}/\mu\text{s}$ $\text{A}/\mu\text{s}$
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$ ; $R_{GK} = \infty$ ; method 1 (linear voltage rise)	$V_{DR} = 2/3 V_{DRM}$	1000	$\text{V}/\mu\text{s}$
$P_{GM}$	$T_{VJ} = T_{VJM}$ $I_T = I_{TAVM}$	$t_p = 30 \mu\text{s}$ $t_p = 300 \mu\text{s}$	10 5	W W
$P_{GAVM}$			0.5	W
$V_{RGM}$			10	V
$T_{VJ}$			-40...+125	$^\circ\text{C}$
$T_{VJM}$			125	$^\circ\text{C}$
$T_{stg}$			-40...+125	$^\circ\text{C}$
$V_{ISOL}$	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ min}$ $t = 1 \text{ s}$	2500 3000	$\text{V}_\sim$ $\text{V}_\sim$
$M_d$	Mounting torque (M5) (10-32 UNF)		$5 \pm 15 \%$ $44 \pm 15 \%$	Nm lb.in.
<b>Weight</b>	typ.		110	g

Data according to IEC 60747 refer to a single thyristor/diode unless otherwise stated.  
IXYS reserves the right to change limits, test conditions and dimensions

Symbol	Test Conditions	Characteristic Values		
$I_D, I_R$	$T_{VJ} = T_{VJM}$ ; $V_R = V_{RRM}$ ; $V_D = V_{DRM}$	≤	5	mA
$V_T$	$I_T = 45 \text{ A}$ ; $T_{VJ} = 25^\circ\text{C}$	≤	1.45	V
$V_{TO}$	For power-loss calculations only	0.85	V	
$r_T$		11	mΩ	
$V_{GT}$	$V_D = 6 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	≤	1.5	V
	$T_{VJ} = -40^\circ\text{C}$	≤	1.6	V
$I_{GT}$	$V_D = 6 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	≤	100	mA
	$T_{VJ} = -40^\circ\text{C}$	≤	200	mA
$V_{GD}$	$T_{VJ} = T_{VJM}$ ; $V_D = 2/3 V_{DRM}$	≤	0.2	V
$I_{GD}$		≤	5	mA
$I_L$	$T_{VJ} = 25^\circ\text{C}$ ; $t_p = 10 \mu\text{s}$ $I_G = 0.45 \text{ A}$ ; $di_G/dt = 0.45 \text{ A}/\mu\text{s}$	≤	450	mA
$I_H$	$T_{VJ} = 25^\circ\text{C}$ ; $V_D = 6 \text{ V}$ ; $R_{GK} = \infty$	≤	200	mA
$t_{gd}$	$T_{VJ} = 25^\circ\text{C}$ ; $V_D = 1/2 V_{DRM}$ $I_G = 0.45 \text{ A}$ ; $di_G/dt = 0.45 \text{ A}/\mu\text{s}$	≤	2	μs
$t_q$	$T_{VJ} = T_{VJM}$ ; $I_T = 20 \text{ A}$ , $t_p = 200 \mu\text{s}$ ; $di/dt = -10 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}$ ; $dv/dt = 15 \text{ V}/\mu\text{s}$ ; $V_D = 2/3 V_{DRM}$	typ.	150	μs
$R_{thJC}$	per thyristor; sine 180°el	0.9	K/W	
	per module	0.15	K/W	
$R_{thJK}$	per thyristor; sine 180°el	1.1	K/W	
	per module	0.183	K/W	
$d_s$	Creeping distance on surface	16.1	mm	
$d_A$	Creepage distance in air	6.0	mm	
$a$	Max. allowable acceleration	50	$\text{m/s}^2$	

### Dimensions in mm (1 mm = 0.0394")

